



AH9247

# HIGH SENSITIVITY MICROPOWER OMNIPOLAR HALL-EFFECT SWITCH

# **Description** Pi

The AH9247 is a high sensitivity Hall-effect switch with internal pull-up resistor on the output, designed for battery-operation, handheld equipments.

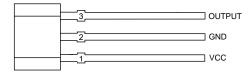
A chopper stabilized amplifier improves stability of magnetic switch points. A sleep-awake logic controls the IC in sleep time or awake time. This function will reduce the average operating current of the IC. During the awake time, the output is changed with the magnetic flux density. During the sleep time, the output is latched in its previous state and the current consumption will reduce to some  $\mu A$ .

The output can be switched on with either north or south pole of sufficient strength. If the magnetic flux density perpendicular to the part marking surface is larger than operating point ( $B_{\text{OP}}$ ), the output will be turned on; if it is less than releasing point ( $B_{\text{RP}}$ ), the output will be turned off.

The AH9247 is available in TO92S (TYPE B), SC59 and DFN-2X2-3 packages which are optimized for most applications.

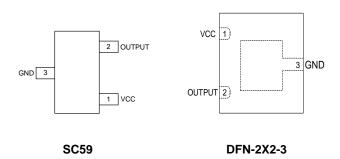
### **Pin Assignments**

#### (Front View)



#### TO92S (TYPE B)

#### (Top View)



#### **Features**

- Micropower Operation
- 2.5V to 5.5V Power Supply
- Switching for Both Poles of a Magnet (Omnipolar)
- Stabilized Chopper
- Superior Temperature Stability
- Digital Output Signal
- Built-in Pull-up Resistor
- ESD (HBM): 6000V
- Small Low Profile DFN-2X2-3 and Industry Standard SC59 and TO92S (TYPE B) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Applications**

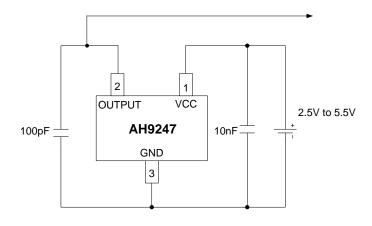
- · Cover Switch in Notebook PC/PDA
- Handheld Wireless Application Awake Switch
- Magnet Switch in Low Duty Cycle Applications

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



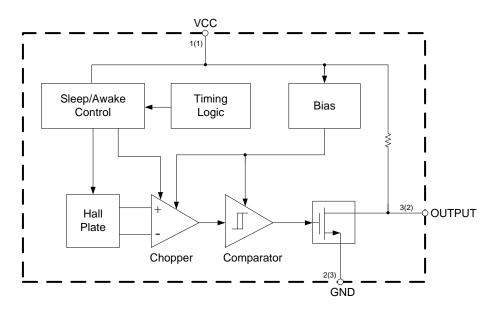
# **Typical Applications Circuit**



# **Pin Descriptions**

	Pin Number		Pin Name	Function
TO92S (TYPE B)	SC59	DFN-2X2-3	Pin Name	Function
1	1	1	VCC	Power supply pin
2	3	3	GND	Ground pin
3	2	2	OUTPUT	Output pin

# **Functional Block Diagram**



A (B) A for TO92S (TYPE B) B for SC59 and DFN-2X2-3



# Absolute Maximum Ratings (@T<sub>A</sub>=+25°C, Note 4)

Symbol	Parameter	Ratin	ıg	Unit
Vcc	Supply Voltage	7		V
Icc	Supply Current (Fault)	6		mA
Vout	Output Voltage	7		V
I <sub>OUT</sub>	Output Current	2		mA
В	Magnetic Flux Density	Unlimited		Gauss
		TO92S (TYPE B)	400	
P <sub>D</sub>	Power Dissipation	SC59	230	mW
		DFN-2X2-3	230	
T <sub>STG</sub>	Storage Temperature	-55 to +	150	°C
TJ	Junction Temperature	+150		°C
_	ESD (Human Body Model) (Note 5) 6000		V	
_	ESD (Machine Model) (Note 5)	400		V

Notes: 4. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

5. Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever

## **Recommended Operating Conditions**

Symbol	ymbol Parameter		Max	Unit
Vcc	Supply Voltage	2.5	5.5	V
T <sub>OP</sub>	Operating Temperature	-40	+85	°C

### Electrical Characteristics (@T<sub>A</sub>=+25°C, V<sub>CC</sub>=3V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	Supply Voltage	Operating	2.5	3	5.5	V
I <sub>AW</sub>		Awake	-	1.8	3	mA
I <sub>SL</sub>	Supply Current	Sleep	-	4	10	μΑ
$I_{AVG}$		Average	_	8	15	μΑ
Гоит	Output Current	-	_	_	1.0	mA
Vsat	Saturation Voltage	I <sub>OUT</sub> =1.0mA	_	_	0.4	V
t <sub>AW</sub>	Awake Mode Time	Operating	-	120	-	μs
t <sub>SL</sub>	Sleep Mode Time	Operating	-	80	120	ms
D	Duty Cycle	-	-	0.15	_	%
f <sub>C</sub>	Chopper Frequency	-	_	15	_	kHz

handling semiconductor products.



## Magnetic Characteristics (@T<sub>A</sub>=+25°C, V<sub>CC</sub>=3V, unless otherwise specified. Note 6)

#### For TO92S (TYPE B) Package

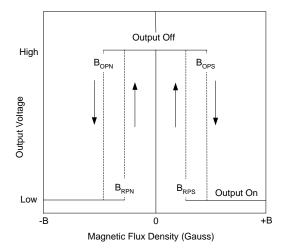
Symbol	Parameter Conditions		Min	Тур	Max	Unit
B <sub>OPS</sub> (South Pole to Part Marking Side)	Operating	B>B <sub>OPS</sub> ,V <sub>OUT</sub> =low(output on)	15	30	55	Gauss
B <sub>OPN</sub> (North Pole to Part Marking Side)	Point	B>B <sub>OPN</sub> ,V <sub>OUT</sub> =low(output on)	-55	-30	-15	Gauss
B <sub>RPS</sub> (South Pole to Part Marking Side)	Releasing	B <b<sub>RPS,V<sub>OUT</sub>=high(output off)</b<sub>	5	20	45	Gauss
B <sub>RPN</sub> (North Pole to Part Marking Side)	Point	B <b<sub>RPN,V<sub>OUT</sub>=high(output off)</b<sub>	-45	-20	-5	Gauss
B <sub>HYS</sub>	Hysteresis	B <sub>OPX</sub> - B <sub>RPX</sub>   (Note 7)	-	10	-	Gauss

#### For SC59 and DFN-2X2-3 Packages

Symbol	Parameter Conditions		Min	Тур	Max	Unit
B <sub>OPS</sub> (South Pole to Part Marking Side)	Operating	B>B <sub>OPS</sub> ,V <sub>OUT</sub> =low(output on)	20	30	40	Gauss
B <sub>OPN</sub> (North Pole to Part Marking Side)	Point	B>B <sub>OPN</sub> ,V <sub>OUT</sub> =low(output on)	-40	-30	-20	Gauss
B <sub>RPS</sub> (South Pole to Part Marking Side)	Releasing	B <b<sub>RPS,V<sub>OUT</sub>=high(output off)</b<sub>	5	20	32	Gauss
B <sub>RPN</sub> (North Pole to Part Marking Side)	Point	B <b<sub>RPN,V<sub>OUT</sub>=high(output off)</b<sub>	-32	-20	-5	Gauss
B <sub>HYS</sub>	Hysteresis	B <sub>OPX</sub> - B <sub>RPX</sub>   (Note 7)	-	10	-	Gauss

Notes:

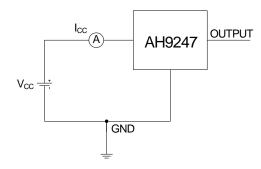
<sup>6.</sup> The specifications stated here are guaranteed by design. 1 Gauss=0.1mT 7.  $B_{OPX}$ =operating point (output turns on);  $B_{RPX}$ =releasing point (output turns off)



**Output Voltage vs. Magnetic Flux Density** 

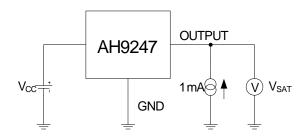


### **Test Conditions**



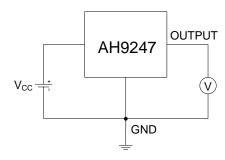
#### **Average Supply Current (Notes 8 and 9)**

Note 8:  $I_{CC}$  represents the average supply current. OUTPUT is open during measurement. Note 9: The device is put under magnetic field with B<B<sub>RP</sub>.



#### **Output Saturation Voltage (Notes 10 and 11)**

Note 10: The output saturation voltage V<sub>SAT</sub> is measured at V<sub>CC</sub>=2.5V and V<sub>CC</sub>=5.5V. Note 11: The device is put under magnetic field with B>B<sub>OP</sub>.



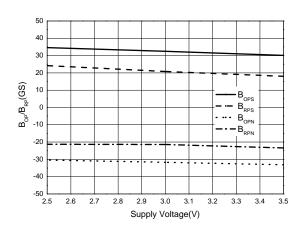
### Magnetic Thresholds (Notes 12 and 13)

Note 12:  $B_{OP}$  is determined by putting the device under magnetic field swept from  $B_{RP(min)}$  to  $B_{OP(max)}$  until the output is switched on. Note 13: B<sub>RP</sub> is determined by putting the device under magnetic field swept from B<sub>OP(max)</sub> to B<sub>RP(min)</sub> until the output is switched off.

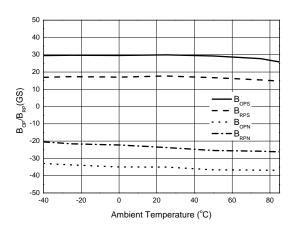


### **Performance Characteristics**

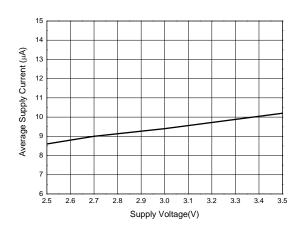
#### B<sub>OP</sub>/B<sub>RP</sub> vs. Supply Voltage



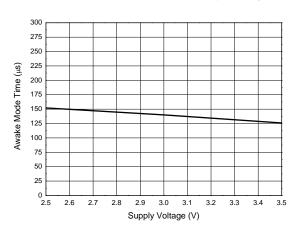
#### B<sub>OP</sub>/B<sub>RP</sub> vs. Ambient Temperature



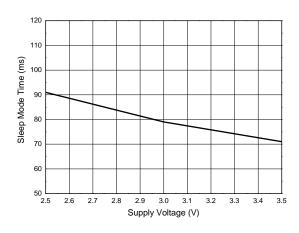
#### **Average Supply Current vs. Supply Voltage**



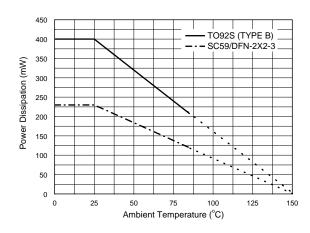
Awake Mode Time vs. Supply Voltage



#### Sleep Mode Time vs. Supply Voltage

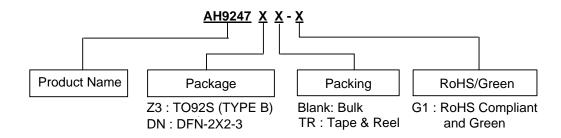


### **Power Dissipation vs. Ambient Temperature**



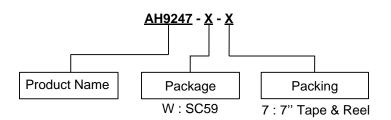


# **Ordering Information**



Device	Status Package Packaging E		Bulk	7" Tape and Reel	
Device	Status	Code	Fackaging	Quantity	Quantity
AH9247Z3-G1	Active	Z3	TO92S (TYPE B)	1000/Bulk	NA
AH9247DNTR-G1	NRND	DN	DFN-2X2-3	NA	3000/Tape & Reel

Note 14: NRND = Not Recommended for New Design.

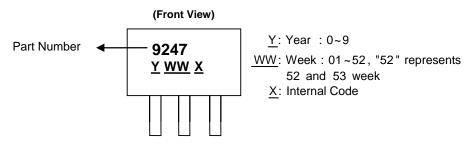


Device	Status	Package	Package Packaging		7" Tape and Reel
Device		Code	Packaging	Quantity	Quantity
AH9247-W-7	Active	W	SC59	NA	3000/Tape & Reel



### **Marking Information**

#### (1) Package Type: TO92S (TYPE B)



Part Number	Package	Identification Code
AH9247	TO92S (TYPE B)	9247

#### (2) Package Type: SC59



XXX YWX

XXX: Identification Code

Y: Year 0 to 9

<u>W</u>: Week: A to Z: 1 to 26 week; a to z: 27 to 52 week; z represents

52 and 53 week X: Internal Code

Part Number	Package	Identification Code
AH9247	SC59	GX8

#### (3) Package Type: DFN-2X2-3

#### (Top View)

 $\underline{Y} \underline{W} \underline{X}$  XX: Identification Code

<u>Y</u> : Year : 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

52 and 53 week X: Internal Code

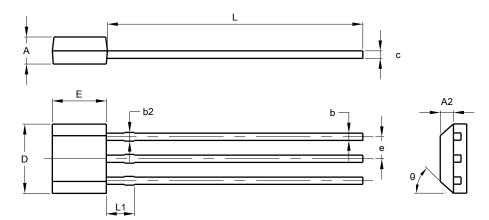
Part Number	Package	Identification Code
AH9247	DFN-2X2-3	JF



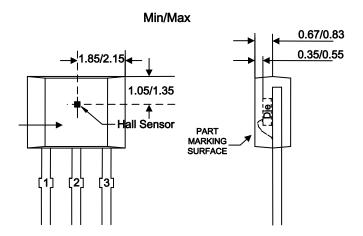
## Package Outline Dimensions (All dimensions in mm(inch).)

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

#### (1) Package Type: TO92S(TYPE B)



	TO92S (TYPE B)						
Dim	Min	Max	Тур				
Α	1.420	1.620	-				
A2	-	-	0.750				
b	0.360	0.480	-				
b2	0.380	0.550	-				
С	0.360	0.510	-				
D	3.850	4.150	-				
Е	2.900	3.310	-				
е	-	-	1.270				
L	14.000	15.500	-				
L1	-	-	1.600				
θ	44°	46°	-				
Α	All Dimensions in mm						



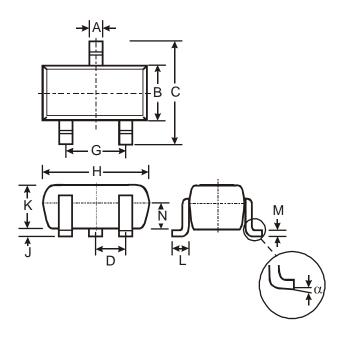
**Sensor Location** 



# Package Outline Dimensions (All dimensions in mm(inch), Cont..)

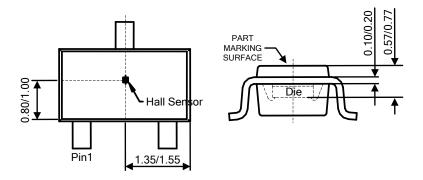
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (2) Package Type: SC59



SC59								
Dim	Min	Max	Тур					
Α	0.35	0.50	0.38					
В	1.50	1.70	1.60					
С	2.70	3.00	2.80					
D	-	-	0.95					
G	-	-	1.90					
Н	2.90	3.10	3.00					
J	0.013	0.10						
K	1.00	1.30	1.10					
L	0.35	0.55	0.40					
M	0.10	0.20	0.15					
N	0.70 0.80		0.75					
α	0°	0° 8° -						
All Dimensions in mm								

#### Min/Max



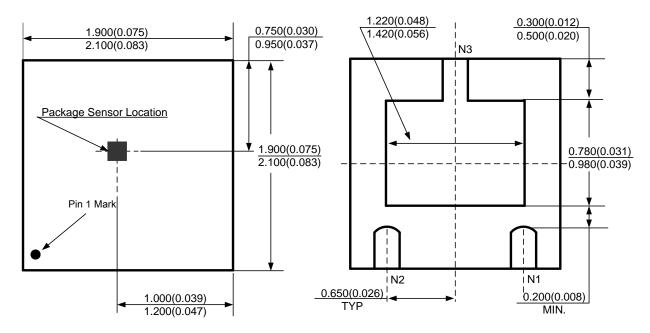
**Sensor Location** 

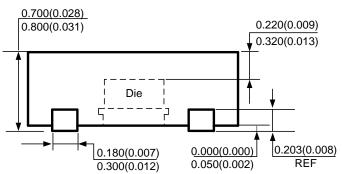


### Package Outline Dimensions (All dimensions in mm(inch), Cont..)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (3) Package Type: DFN-2X2-3



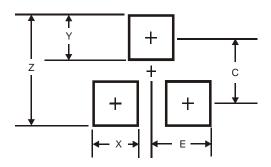




# Suggested Pad Layout

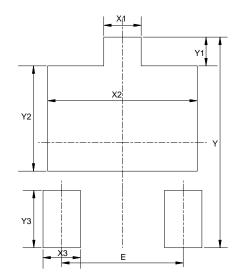
Please see http://www.diodes.com/package-outlines.html for the latest version.

### (1) Package Type: SC59



Dimensions	Value (in mm)		
Z	3.4		
Х	0.8		
Y	1.0		
С	2.4		
E	1.35		

### (2) Package Type: DFN-2X2-3



Dimensions	Y	X1=X3	Y1	X2	Y2	Y3	E
	(mm)/(inch)						
Value	2.200/0.087	0.400/0.016	0.300/0.012	1.600/0.063	1.100/0.043	0.600/0.024	1.300/0.051



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